Random laser action in self-organized para-sexiphenyl nanofibers grown by hot-wall epitaxy

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We report on the observation of amplified spontaneous emission and random lasing in self-organized crystalline para-sexiphenyl nanofibers. Using subpicosecond excitation, a lasing threshold is observed on the 0–1 emission band near 425 nm at excitation fluences as low as 0.5 µJ/cm² (6 × 10¹⁶ cm⁻³ equivalent density), near the onset of density-dependent recombination processes. The dependence of the nonlinear emission spectrum on both the pump intensity and position of the excitation area are attributed to the interplay between random lasing and amplified spontaneous emission occurring along the nanofibers. © 2004 American Institute of Physics.

Conjugated polymers and oligomers have become increasingly interesting materials for applications in different optoelectronic devices, such as field-effect transistors, photovoltaic cells, light-emitting diodes, and potentially, laser diodes. In the perspective to achieve electrical pumping in light-amplifying organic devices, the research on new organic active materials has been focused on the study of amplified spontaneous emission (ASE) and lasing processes with photopumping techniques. ASE and laser action have been reported so far in a number of polymeric and dye-doped organic thin films embedded in optical waveguides with different solutions for the laser cavity mirrors. 1–4 Oligomers offer clear advantages over polymers for applications involving highly ordered structures. ASE has been observed in oligo-thiophene, 5 oligo-(phenylene vinylene), 6 and related co-oligomer 7 single crystals; however, it has not been reported in the case of polycrystalline films with small domains, due to high optical losses occurring at the interfaces between different grain domains. 6 In recent years, various groups have fabricated self-organized crystalline nanofibers of oligo-phenylenes with the potential for future applications in photonics as nanoscale laser sources. 8–10 Investigations of the nonlinear optical response of oligo-phenylene nanofibers have shown so far only evidence of spectral narrowing. 11

In this letter, we report on the observation of random laser action in crystalline para-sexiphenyl (p-6P). Crystalline nanofibers of p-6P are grown by hot-wall epitaxy (HWE) on freshly cleaved mica substrates, under a dynamic vacuum of 10⁻⁶ mbar, at a substrate temperature of 130 °C. Under these conditions, p-6P molecules self-organize in very long (more than ~100 µm) 9 needle-shaped nanofibers, which in turn consist of crystalline domains showing three different epitaxial relationships to the mica substrate. 12 Importantly, the alignment of the p-6P long molecular axes is nearly the same in all domains—practically parallel to the substrate and perpendicular to the fiber direction. 9,12 Such a uniform alignment of molecules reflects in very high dichroic ratios of p-6P nano-fibers—up to 14 in absorption and emission, 9 as well as in waveguiding behavior of single nanofibers. 13

Samples with different quantities of deposited material are grown, resulting in nanofibers with different average heights, ranging from 100 to 400 nm. The p-6P nanocrystals are photoexcited with the frequency-doubled pulses (at 380 nm) of a Ti:Sapphire regenerative amplifier delivering 150 fs long pulses at 1 kHz repetition rate. Laser spot sizes of ~120 µm (diameter) are used for photoexcitation. The samples are mounted in a recirculating-loop cold-finger cryostat for low-temperature measurements. The optical emission is collected at different angles with respect to the normal to the substrate, then dispersed in a 46 cm single spectrometer and detected by a cooled charge-coupled device.

Figure 1 shows the surface morphology of the sample used to obtain the results presented in this letter. A line profile made nearly diagonally (so as to intersect the fibers perpendicularly) shows an average base width (b) and height near 2.5 µm.

FIG. 1. 10×10 µm AFM topography image of the surface morphology of a p-6P film grown by HWE at 130 °C on mica.

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FIG. 2. Main panel: Emission spectra taken at different values of the pump fluence \( \Phi (\mu J/cm^2 per pulse) \) at \( T=30 \) K. Inset: Emission spectra measured in two different positions across the sample surface at the same excitation level above threshold (\( T=300 \) K).

\( \langle h \rangle \) of the nanofibers of about 220 nm and 110 nm, respectively. The fraction of substrate surface covered with fibers is estimated to be \( \approx 50\% \). Based on the results of recent calculations of the propagation modes of \( p-6P \) waveguides,\(^\text{13}\) we hereafter assume that the \( p-6P \) emission near 425 nm propagates with possible amplification only in the (widest) fibers with \( b>200–250 \) nm.

The sample is photoexcited at normal incidence with the laser beam polarization set parallel to the long axis of the \( p-6P \) molecules, so that a maximum material absorption of \( \approx 60\% \) is achieved. The emission is found to be rather isotropic, due to both light diffraction at the exit of the nanofibers and disorder-induced light scattering. Nevertheless, the emission features a degree of polarization.

FIG. 3. Panel (a): SI emission intensity vs photoexcited density \( N_0 \), for pump intensities below threshold (\( T=30 \) K). The solid dots are the experimental points and the solid line is a fit to the data using Eq. (1). Panel (b): SI random lasing plus stimulated emission intensity versus normalized pump excess fluence \( \Delta \Phi/\Phi_\text{th} (T=300 \) K). Panel (c): Emission spectra recorded at \( \Delta \Phi/\Phi_\text{th} =0.58 \) and 9.0 (\( T=300 \) K).

The data actually refer to a position on the sample with a threshold density \( N_{\text{th}} =2 \times 10^{17} \) cm\(^{-3} \). The sublinear dependence of the signal versus \( N_0 \) indicates that threshold is achieved in the regime of (nonradiative) bimolecular recombination for the photexcited density. An estimate of the bimolecular recombination rate can be obtained by data fitting. The time-integrated emission intensity (\( S_{\text{TI}} \)) has the form:

\[
S_{\text{TI}} \propto \int N(t) \, dt \sim \ln \left( \frac{k_{\text{ss}} N_0}{k_0} + 1 \right),
\]

where \( k_{ss} \) and \( k_0 \) are the bimolecular recombination rate and the (low-intensity) inverse photoluminescence lifetime, respectively. From data fitting using the expression given in Eq. (1) and \( k_0 = 1.8 \times 10^9 \) s\(^{-1}\),\(^\text{17}\) we find \( k_{ss} = (0.9 \pm 0.2) \times 10^{-7} \) cm\(^3\)/s. By comparing data sets obtained in different positions on the sample, we determine that the value of \( k_{ss} \) lies in the interval (0.5–1.1) \times 10^{-7} \) cm\(^3\)/s. The bimolecular recombination rate (and so the exciton diffusion coefficient) of crystalline \( p-6P \) are thus found to be of the same order of magnitude as that reported in literature for crystalline tetracene.\(^\text{18}\)

For excitation levels just above threshold, laser action first takes place in a few nanofibers featuring efficient random feedback and long gain paths. Thanks to their narrow linewidth, random modes emerge from the intense spontaneous...
ous emission spectrum resulting from all the other fibers, which are characterized by higher optical losses. These latter represent the majority of the crystalline needles. The evolution of the emission spectrum as a function of the excitation power is in fact very similar to that reported in an ensemble of dye-filled microcrystals, where laser oscillation begins on a single crystal, while all the other microresonators, supporting lossier modes, contribute to the ensemble response with spontaneous emission only.\(^{19}\) The emission intensity for excitation levels above \(\Phi_{\text{th}}\) is plotted in Fig. 3(b) as a function of the normalized pump excess fluence, defined as \(\Delta\Phi/\Phi_{\text{th}} = (\Phi - \Phi_{\text{th}})/\Phi_{\text{th}}\). The signal is spectrally integrated over the random lasing spectrum, after subtraction of the spontaneous emission contribution. The emission varies superlinearly with \(\Delta\Phi/\Phi_{\text{th}}\). At small values of \(\Delta\Phi/\Phi_{\text{th}}\), the number of oscillating modes increases with increasing pump fluence, since different random modes are characterized by different lasing thresholds.\(^{16}\) As a consequence, the total emission of the narrow lines increases superlinearly with increasing \(\Delta\Phi/\Phi_{\text{th}}\). Eventually, ASE is achieved along nanofibers with higher optical losses and not contributing to lasing. The rise of an ASE band explains: (i) The persistence of the superlinear growth of the emission intensity\(^{15}\) and (ii) the progressive decrease in visibility of the random lasing modes at large values of \(\Delta\Phi/\Phi_{\text{th}}\), as shown in Fig. 3(c).

In summary, we report experimental evidence of random laser action in crystalline \(p\)-6P consisting of self-organized nanofibers. Threshold fluences as low as 0.5 \(\mu\text{J/cm}^2\) (6 \(\times\) 10\(^{16}\) \(\text{cm}^{-3}\) equivalent threshold densities) are observed near 425 nm with subpicosecond pulses as the excitation source. Our studies allow for the estimate of intrinsic material parameters, such as the bimolecular recombination rate which is found to be as high as \(10^{-7}\) \(\text{cm}^3/\text{s}\).

In spite of the high \(p\)-6P crystalline order, the onset of density-dependent recombination processes occurs at a density which is only a factor of 2–3 lower than the lowest threshold density we observed. Moreover, a threshold density \(N_{\text{th}} = 6 \times 10^{16} \text{cm}^{-3}\) yields an equivalent threshold current density \((J_{\text{th}})\) of \(\approx 2\)–3 \(\text{kA/cm}^2\) in continuous-wave operation, assuming a singlet-to-triplet injection ratio of 0.3 and no additional density-dependent loss mechanisms other than bimolecular recombination. Current densities of the order of \(J_{\text{th}}\) could be sustainable in organic crystals\(^{20}\) suggesting that electrical pumping is potentially feasible in crystalline \(p\)-6P. We conclude that highly ordered oligomer crystals are very promising as gain materials for future nanoscale optoelectronic and photonic devices.

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17. The value of \(k_0\) is deduced from photoluminescence lifetime measurements made on the same nanofibers.